

# ISO723xx High-Speed, Triple-Channel Digital Isolators

## 1 Features

- 25 and 150Mbps signaling rate options
  - Low channel-to-channel output skew; 1ns maximum
  - Low pulse-width distortion (PWD); 2ns maximum
  - Low jitter content; 1ns typical at 150Mbps
- Typical 25-Year Life at Rated Working Voltage (see [Isolation Lifetime Projection](#))
- 4kV ESD protection
- Operate with 3.3V or 5V supplies
- 3.3V and 5V level translation
- High electromagnetic immunity
- –40°C to 125°C operating range
- [Safety Related Certifications](#)
  - [DIN EN IEC 60747-17 \(VDE 0884-17\) conformity per VDE](#)
  - [UL 1577 component recognition program](#)
  - [IEC 61010-1, IEC 62368-1 certifications](#)

## 2 Applications

- [Factory Automation](#)
  - [Modbus](#)
  - [Profibus™](#)
  - [DeviceNet™ Data Buses](#)
- [Computer Peripheral Interface](#)
- [Servo Control Interface](#)
- [Data Acquisition](#)

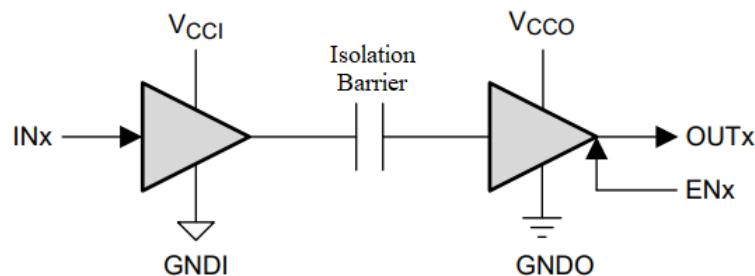
## 3 Description

The ISO7230 and ISO7231 are triple-channel digital isolators each with multiple channel configurations and output enable functions. These devices have logic input and output buffers separated by TI's silicon dioxide (SiO<sub>2</sub>) isolation barrier. Used in conjunction with isolated power supplies, these devices block high voltage, isolate grounds, and prevent noise currents on a data bus or other circuits from entering the local ground and interfering with or damaging sensitive circuitry.

### Package Information

| PART NUMBER                      | PACKAGE <sup>(1)</sup> | BODY SIZE (NOM)  | PACKAGE SIZE <sup>(2)</sup> |
|----------------------------------|------------------------|------------------|-----------------------------|
| ISO7230C<br>ISO7231C<br>ISO7231M | DW (SOIC, 16)          | 10.30mm × 7.50mm | 10.30mm × 10.30mm           |

- (1) For all available packages, see the orderable addendum at the end of the data sheet.
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.



- A. V<sub>CCI</sub> and GNDI are supply and ground connections respectively for the input channels.
- B. V<sub>CCO</sub> and GNDO are supply and ground connections respectively for the output channels.

### Simplified Schematic



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## 4 Device Comparison Table

| PRODUCT  | SIGNALING RATE | INPUT THRESHOLD                            | CHANNEL CONFIGURATION | ISOLATION RATING                                |
|----------|----------------|--------------------------------------------|-----------------------|-------------------------------------------------|
| ISO7230C | 25 Mbps        | $\approx 1.5$ V (TTL)<br>(CMOS compatible) | 3/0                   | 4000 V <sub>PK</sub> ,<br>2500 V <sub>RMS</sub> |
| ISO7231C | 25 Mbps        | $\approx 1.5$ V (TTL)<br>(CMOS compatible) | 2/1                   |                                                 |
| ISO7231M | 150 Mbps       | V <sub>CC</sub> /2 (CMOS)                  |                       |                                                 |

## 5 Pin Configuration and Functions

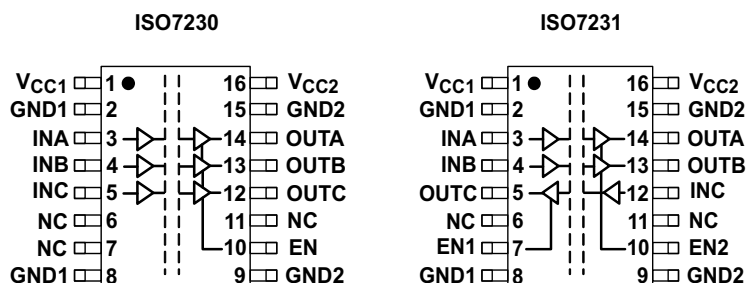


Figure 5-1. DW Package 16-Pin SOIC Top View

Table 5-1. Pin Functions

| NAME             | PIN      |         | TYPE <sup>(1)</sup> | DESCRIPTION                            |
|------------------|----------|---------|---------------------|----------------------------------------|
|                  | ISO7230  | ISO7231 |                     |                                        |
| EN               | 10       | —       | I                   | Enable, channel A, B, and C            |
| EN1              | —        | 7       | I                   | Enable, channel C                      |
| EN2              | —        | 10      | I                   | Enable, channel A and B                |
| GND1             | 2, 8     | 2, 8    | —                   | Ground connection for V <sub>CC1</sub> |
| GND2             | 9, 15    | 9, 15   | —                   | Ground connection for V <sub>CC2</sub> |
| INA              | 3        | 3       | I                   | Input, channel A                       |
| INB              | 4        | 4       | I                   | Input, channel B                       |
| INC              | 5        | 12      | I                   | Input, channel C                       |
| NC               | 6, 7, 11 | 6, 11   | —                   | Not connected                          |
| OUTA             | 14       | 14      | O                   | Output, channel A                      |
| OUTB             | 13       | 13      | O                   | Output, channel B                      |
| OUTC             | 12       | 5       | O                   | Output, channel C                      |
| V <sub>CC1</sub> | 1        | 1       | —                   | Power supply, V <sub>CC1</sub>         |
| V <sub>CC2</sub> | 16       | 16      | —                   | Power supply, V <sub>CC2</sub>         |

(1) I = Input; O = Output

## 6 Specifications

### 6.1 Absolute Maximum Ratings

See<sup>(1)</sup>

|                  |                                                                     | MIN  | MAX                                  | UNIT |
|------------------|---------------------------------------------------------------------|------|--------------------------------------|------|
| V <sub>CC</sub>  | Supply voltage <sup>(2)</sup> , V <sub>CC1</sub> , V <sub>CC2</sub> | –0.5 | 6                                    | V    |
| V <sub>I</sub>   | Voltage at INx, OUTx, ENx                                           | –0.5 | V <sub>CC</sub> + 0.5 <sup>(3)</sup> | V    |
| I <sub>O</sub>   | Output current                                                      | –15  | 15                                   | mA   |
| T <sub>J</sub>   | Maximum junction temperature                                        |      | 170                                  | °C   |
| T <sub>stg</sub> | Storage temperature                                                 | –65  | 150                                  | °C   |

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) All voltage values are with respect to network ground terminal and are peak voltage values.
- (3) Maximum voltage must not exceed 6 V.

### 6.2 ESD Ratings

|                    |                         |                                                                                | VALUE | UNIT |
|--------------------|-------------------------|--------------------------------------------------------------------------------|-------|------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±4000 | V    |
|                    |                         | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±1000 |      |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | ISO7230C,<br>ISO7231C, ISO7231M | UNIT |
|-------------------------------|----------------------------------------------|---------------------------------|------|
|                               |                                              | DW (SOIC)                       |      |
|                               |                                              | 16 PINS                         |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 168                             | °C/W |
|                               |                                              | 68.6                            | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    | 33.9                            | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 33.5                            | °C/W |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 14.8                            | °C/W |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 32.9                            | °C/W |
| R <sub>θJC(bot)</sub>         | Junction-to-case (bottom) thermal resistance | n/a                             | °C/W |

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

## 6.4 Recommended Operating Conditions

|                   |                                                                                             |          | MIN                   | NOM | MAX                   | UNIT |
|-------------------|---------------------------------------------------------------------------------------------|----------|-----------------------|-----|-----------------------|------|
| V <sub>CC</sub>   | Supply voltage <sup>(2)</sup> , V <sub>CC1</sub> , V <sub>CC2</sub>                         |          | 3.15                  |     | 5.5                   | V    |
| I <sub>OH</sub>   | High-level output current                                                                   |          | –4                    |     |                       | mA   |
| I <sub>OL</sub>   | Low-level output current                                                                    |          |                       |     | 4                     | mA   |
| t <sub>ui</sub>   | Input pulse width <sup>(1)</sup>                                                            | ISO723xC | 40                    |     |                       | ns   |
| t <sub>ui</sub>   | Input pulse width <sup>(1)</sup>                                                            | ISO723xM | 6.67                  | 5   |                       | ns   |
| 1/t <sub>ui</sub> | Signaling rate <sup>(1)</sup>                                                               | ISO723xC | 0                     | 30  | 25                    | Mbps |
| 1/t <sub>ui</sub> | Signaling rate <sup>(1)</sup>                                                               | ISO723xM | 0                     | 200 | 150                   | Mbps |
| V <sub>IH</sub>   | High-level input voltage                                                                    | ISO723xM | 0.7 x V <sub>CC</sub> |     | V <sub>CC</sub>       | V    |
| V <sub>IL</sub>   | Low-level input voltage                                                                     | ISO723xM | 0                     |     | 0.3 x V <sub>CC</sub> | V    |
| V <sub>IH</sub>   | High-level input voltage                                                                    | ISO723xC | 2                     |     | 5.5                   | V    |
| V <sub>IL</sub>   | Low-level input voltage                                                                     | ISO723xC | 0                     |     | 0.8                   | V    |
| T <sub>A</sub>    | Ambient temperature                                                                         |          | –40                   | 25  | 125                   |      |
| T <sub>J</sub>    | Junction temperature                                                                        |          |                       |     | 150                   | °C   |
| H                 | External magnetic field-strength immunity per IEC 61000-4-8 and IEC 61000-4-9 certification |          |                       |     | 1000                  | A/m  |

(1) Typical signaling rate and Input pulse width are measured at ideal conditions at 25°C.

(2) For the 5-V operation, V<sub>CC1</sub> or V<sub>CC2</sub> is specified from 4.5 V to 5.5 V.

For the 3.3-V operation, V<sub>CC1</sub> or V<sub>CC2</sub> is specified from 3 V to 3.6 V.

For the 2.8-V operation, V<sub>CC1</sub> or V<sub>CC2</sub> is specified at 2.8 V.

## 6.5 Power Ratings

over operating free-air temperature range (unless otherwise noted)

| PARAMETER      |                                                                                                                                                                      | ISO7230C, ISO7231C, ISO7231M | UNIT |
|----------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------|------|
|                |                                                                                                                                                                      | DW (SOIC)                    |      |
|                |                                                                                                                                                                      | 16 PINS                      |      |
| P <sub>D</sub> | Device power dissipation, V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5 V, T <sub>J</sub> = 150°C, C <sub>L</sub> = 15 pF, D Input a 50% duty cycle, 25-Mbps square wave | 220                          | mW   |

## 6.6 Insulation Specifications

| PARAMETER                                       |                                                      | TEST CONDITIONS                                                                                                                                                                                                                                                                                   | VALUE             | UNIT             |
|-------------------------------------------------|------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|------------------|
| GENERAL                                         |                                                      |                                                                                                                                                                                                                                                                                                   |                   |                  |
| CLR                                             | External clearance <sup>(1)</sup>                    | Shortest terminal-to-terminal distance through air                                                                                                                                                                                                                                                | 8                 | mm               |
| CPG                                             | External creepage <sup>(1)</sup>                     | Shortest terminal-to-terminal distance across the package surface                                                                                                                                                                                                                                 | 8                 | mm               |
| DTI                                             | Distance through the insulation                      | Minimum internal gap (internal clearance)                                                                                                                                                                                                                                                         | 0.008             | mm               |
| CTI                                             | Comparative tracking index                           | DIN EN 60112 (VDE 0303-11); IEC 60112                                                                                                                                                                                                                                                             | ≥400              | V                |
|                                                 | Material group                                       |                                                                                                                                                                                                                                                                                                   | II                |                  |
|                                                 | Overvoltage category                                 | Rated mains voltage ≤150 V <sub>RMS</sub>                                                                                                                                                                                                                                                         | I-IV              |                  |
|                                                 |                                                      | Rated mains voltage ≤300 V <sub>RMS</sub>                                                                                                                                                                                                                                                         | I-III             |                  |
|                                                 |                                                      | Rated mains voltage ≤400 V <sub>RMS</sub>                                                                                                                                                                                                                                                         | I-II              |                  |
| DIN EN IEC 60747-17 (VDE 0884-17): <sup>2</sup> |                                                      |                                                                                                                                                                                                                                                                                                   |                   |                  |
| V <sub>IORM</sub>                               | Maximum repetitive peak isolation voltage            | AC voltage (bipolar)                                                                                                                                                                                                                                                                              | 560               | V <sub>PK</sub>  |
| V <sub>IOTM</sub>                               | Maximum transient isolation voltage                  | V <sub>TEST</sub> = V <sub>IOTM</sub> , t = 60 s (qualification);<br>V <sub>TEST</sub> = 1.2 x V <sub>IOTM</sub> , t = 1 s (100% production)                                                                                                                                                      | 4000              | V <sub>PK</sub>  |
| q <sub>pd</sub>                                 | Apparent charge <sup>(3)</sup>                       | Method a: After I/O safety test subgroup 2/3<br>V <sub>ini</sub> = V <sub>IOTM</sub> , t <sub>ini</sub> = 60 s;<br>V <sub>pd(m)</sub> = 1.2 x V <sub>IORM</sub> , t <sub>m</sub> = 10 s                                                                                                           | ≤5                | pC               |
|                                                 |                                                      | Method a: After environmental tests subgroup 1<br>V <sub>ini</sub> = V <sub>IOTM</sub> , t <sub>ini</sub> = 60 s;<br>V <sub>pd(m)</sub> = 1.3 x V <sub>IORM</sub> , t <sub>m</sub> = 10 s                                                                                                         | ≤5                |                  |
|                                                 |                                                      | Method b: At routine test (100% production);<br>V <sub>ini</sub> = 1.2 x V <sub>IOTM</sub> , t <sub>ini</sub> = 1s;<br>V <sub>pd(m)</sub> = 1.5 x V <sub>IORM</sub> , t <sub>m</sub> = 1s (method b1) or<br>V <sub>pd(m)</sub> = V <sub>ini</sub> , t <sub>m</sub> = t <sub>ini</sub> (method b2) | ≤5                |                  |
| C <sub>IO</sub>                                 | Barrier capacitance, input to output <sup>(4)</sup>  | V <sub>IO</sub> = 0.4 x sin (2πft), f = 1 MHz                                                                                                                                                                                                                                                     | 1                 | pF               |
| R <sub>IO</sub>                                 | Isolation resistance, input to output <sup>(4)</sup> | V <sub>IO</sub> = 500 V, T <sub>A</sub> = 25°C                                                                                                                                                                                                                                                    | >10 <sup>12</sup> | Ω                |
|                                                 |                                                      | V <sub>IO</sub> = 500 V, 100°C ≤ T <sub>A</sub> ≤ 125°C                                                                                                                                                                                                                                           | >10 <sup>11</sup> |                  |
|                                                 |                                                      | V <sub>IO</sub> = 500 V at T <sub>S</sub> = 150°C                                                                                                                                                                                                                                                 | >10 <sup>9</sup>  |                  |
|                                                 | Pollution degree                                     |                                                                                                                                                                                                                                                                                                   | 2                 |                  |
|                                                 | Climatic category                                    |                                                                                                                                                                                                                                                                                                   | 40/125/21         |                  |
| UL 1577                                         |                                                      |                                                                                                                                                                                                                                                                                                   |                   |                  |
| V <sub>ISO</sub>                                | Withstand isolation voltage                          | V <sub>TEST</sub> = V <sub>ISO</sub> = 2500 V <sub>RMS</sub> , t = 60 s (qualification);<br>V <sub>TEST</sub> = 1.2 x V <sub>ISO</sub> = 3000 V <sub>RMS</sub> , t = 1 s (100% production)                                                                                                        | 2500              | V <sub>RMS</sub> |

- (1) Creepage and clearance requirements should be applied according to the specific equipment isolation standards of an application. Care should be taken to maintain the creepage and clearance distance of a board design to ensure that the mounting pads of the isolator on the printed-circuit board do not reduce this distance. Creepage and clearance on a printed-circuit board become equal in certain cases. Techniques such as inserting grooves and/or ribs on a printed circuit board are used to help increase these specifications.
- (2) This coupler is suitable for *basic electrical insulation* only within the maximum operating ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.
- (3) Apparent charge is electrical discharge caused by a partial discharge (pd).
- (4) All pins on each side of the barrier tied together creating a two-terminal device

## 6.7 Safety-Related Certifications

| VDE                                                      | CSA                                | UL                                                           |
|----------------------------------------------------------|------------------------------------|--------------------------------------------------------------|
| Certified according to DIN EN IEC 60747-17 (VDE 0884-17) | Certified according to IEC 62368-1 | Certified according to UL 1577 Component Recognition Program |
| Basic certificate: 40047657                              | Master contract number: 220991     | File number: E181974                                         |

## 6.8 Safety Limiting Values

Safety limiting<sup>(1)</sup> intends to minimize potential damage to the isolation barrier upon failure of input or output circuitry. A failure of the I/O can allow low resistance to ground or the supply and, without current limiting, dissipate sufficient power to overheat the die and damage the isolation barrier, potentially leading to secondary system failures.

| PARAMETER      |                                         | TEST CONDITIONS                                                                                                                    | MIN | TYP | MAX | UNIT |
|----------------|-----------------------------------------|------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|------|
| I <sub>S</sub> | Safety input, output, or supply current | R <sub>θJA</sub> = 212°C/W, V <sub>I</sub> = 5.5 V, T <sub>J</sub> = 170°C, T <sub>A</sub> = 25°C, see <a href="#">Section 6.3</a> |     |     | 124 | mA   |
|                |                                         | R <sub>θJA</sub> = 212°C/W, V <sub>I</sub> = 3.6 V, T <sub>J</sub> = 170°C, T <sub>A</sub> = 25°C, see <a href="#">Section 6.3</a> |     |     | 190 |      |
| T <sub>S</sub> | Safety temperature                      |                                                                                                                                    |     |     | 150 | °C   |

- (1) The safety-limiting constraint is the maximum junction temperature specified in the data sheet. The power dissipation and junction-to-air thermal impedance of the device installed in the application hardware determines the junction temperature. The assumed junction-to-air [thermal resistance](#) in the table is that of a device installed on a high-K test board for leaded surface-mount packages. The power is the recommended maximum input voltage times the current. The junction temperature is then the ambient temperature plus the power times the junction-to-air thermal resistance.

## 6.9 Electrical Characteristics: V<sub>CC1</sub> and V<sub>CC2</sub> at 3.3 V

over recommended operating conditions (unless otherwise noted)<sup>(1)</sup>

| PARAMETER                  |                                |           | TEST CONDITIONS                                                                         | MIN                    | TYP  | MAX | UNIT  |
|----------------------------|--------------------------------|-----------|-----------------------------------------------------------------------------------------|------------------------|------|-----|-------|
| SUPPLY CURRENT             |                                |           |                                                                                         |                        |      |     |       |
| I <sub>CC1</sub>           | ISO7230C/M                     | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN at 3 V              |                        | 0.5  | 1.2 | mA    |
|                            |                                | 25 Mbps   |                                                                                         |                        | 3    | 5   |       |
|                            | ISO7231C/M                     | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN1 at 3 V, EN2 at 3 V |                        | 4.5  | 7   | mA    |
|                            |                                | 25 Mbps   |                                                                                         |                        | 6.5  | 11  |       |
| I <sub>CC2</sub>           | ISO7230C/M                     | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN at 3 V              |                        | 9    | 15  | mA    |
|                            |                                | 25 Mbps   |                                                                                         |                        | 10   | 17  |       |
|                            | ISO7231C/M                     | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN1 at 3 V, EN2 at 3 V |                        | 8    | 12  | mA    |
|                            |                                | 25 Mbps   |                                                                                         |                        | 10.5 | 16  |       |
| ELECTRICAL CHARACTERISTICS |                                |           |                                                                                         |                        |      |     |       |
| I <sub>OFF</sub>           | Sleep mode output current      |           | ENx at 0 V, single channel                                                              | 0                      |      |     | μA    |
| V <sub>OH</sub>            | High-level output voltage      |           | I <sub>OH</sub> = −4 mA, See <a href="#">Figure 7-1</a>                                 | V <sub>CCO</sub> − 0.4 |      |     | V     |
|                            |                                |           | I <sub>OH</sub> = −20 μA, See <a href="#">Figure 7-1</a>                                | V <sub>CCO</sub> − 0.1 |      |     |       |
| V <sub>OL</sub>            | Low-level output voltage       |           | I <sub>OL</sub> = 4 mA, See <a href="#">Figure 7-1</a>                                  | 0.4                    |      |     | V     |
|                            |                                |           | I <sub>OL</sub> = 20 μA, See <a href="#">Figure 7-1</a>                                 | 0.1                    |      |     |       |
| V <sub>I(HYS)</sub>        | Input voltage hysteresis       |           |                                                                                         | 150                    |      |     | mV    |
| I <sub>IH</sub>            | High-level input current       |           | INx at V <sub>CC1</sub>                                                                 | 10                     |      |     | μA    |
| I <sub>IL</sub>            | Low-level input current        |           | INx at 0 V                                                                              | −10                    |      |     |       |
| C <sub>I</sub>             | Input capacitance to ground    |           | IN at V <sub>CC</sub> , V <sub>I</sub> = 0.4 sin (2πft), f=2MHz                         | 2                      |      |     | pF    |
| CMTI                       | Common-mode transient immunity |           | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, See <a href="#">Figure 7-4</a>                | 25                     | 50   |     | kV/μs |

- (1) For the 5-V operation, V<sub>CC1</sub> or V<sub>CC2</sub> is specified from 4.5 V to 5.5 V.  
For the 3.3-V operation, V<sub>CC1</sub> or V<sub>CC2</sub> is specified from 3.15 V to 3.6 V.

## 6.10 Electrical Characteristics: $V_{CC1}$ and $V_{CC2}$ at 5-V

over recommended operating conditions (unless otherwise noted)<sup>(1)</sup>

| PARAMETER                  |                                |           | TEST CONDITIONS                                                                         | MIN                    | TYP  | MAX | UNIT  |
|----------------------------|--------------------------------|-----------|-----------------------------------------------------------------------------------------|------------------------|------|-----|-------|
| SUPPLY CURRENT             |                                |           |                                                                                         |                        |      |     |       |
| I <sub>CC1</sub>           | ISO7230C/M                     | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN at 3 V              |                        | 1    | 3   | mA    |
|                            |                                | 25 Mbps   |                                                                                         |                        | 7    | 9.5 |       |
|                            | ISO7231C/M                     | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN1 at 3 V, EN2 at 3 V |                        | 6.5  | 11  | mA    |
|                            |                                | 25 Mbps   |                                                                                         |                        | 11   | 17  |       |
| I <sub>CC2</sub>           | ISO7230C/M                     | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN at 3 V              |                        | 15   | 22  | mA    |
|                            |                                | 25 Mbps   |                                                                                         |                        | 17   | 24  |       |
|                            | ISO7231C/M                     | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN1 at 3 V, EN2 at 3 V |                        | 13   | 20  | mA    |
|                            |                                | 25 Mbps   |                                                                                         |                        | 17.5 | 27  |       |
| ELECTRICAL CHARACTERISTICS |                                |           |                                                                                         |                        |      |     |       |
| I <sub>OFF</sub>           | Sleep mode output current      |           | ENx at 0 V, single channel                                                              |                        | 0    |     | μA    |
| V <sub>OH</sub>            | High-level output voltage      |           | I <sub>OH</sub> = −4 mA, See <a href="#">Figure 7-1</a>                                 | V <sub>CCO</sub> − 0.8 |      |     | V     |
|                            |                                |           | I <sub>OH</sub> = −20 μA, See <a href="#">Figure 7-1</a>                                | V <sub>CCO</sub> − 0.1 |      |     |       |
| V <sub>OL</sub>            | Low-level output voltage       |           | I <sub>OL</sub> = 4 mA, See <a href="#">Figure 7-1</a>                                  |                        |      | 0.4 | V     |
|                            |                                |           | I <sub>OL</sub> = 20 μA, See <a href="#">Figure 7-1</a>                                 |                        |      | 0.1 |       |
| V <sub>I(HYS)</sub>        | Input voltage hysteresis       |           |                                                                                         |                        | 150  |     | mV    |
| I <sub>IH</sub>            | High-level input current       |           | INx at V <sub>CC1</sub>                                                                 |                        |      | 10  | μA    |
| I <sub>IL</sub>            | Low-level input current        |           | INx at 0 V                                                                              | −10                    |      |     |       |
| C <sub>I</sub>             | Input capacitance to ground    |           | IN at V <sub>CC</sub> , V <sub>I</sub> = 0.4 sin (2πft), f=2MHz                         |                        | 2    |     | pF    |
| CMTI                       | Common-mode transient immunity |           | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, See <a href="#">Figure 7-4</a>                | 25                     | 50   |     | kV/μs |

- (1) For the 5-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 4.5 V to 5.5 V.  
For the 3.3-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 3.15 V to 3.6 V.

## 6.11 Electrical Characteristics: $V_{CC1}$ at 3.3-V, $V_{CC2}$ at 5-V

over recommended operating conditions (unless otherwise noted)<sup>(1)</sup>

| PARAMETER                  |                             |           | TEST CONDITIONS                                                                         |  | MIN                | TYP                    | MAX | UNIT |
|----------------------------|-----------------------------|-----------|-----------------------------------------------------------------------------------------|--|--------------------|------------------------|-----|------|
| SUPPLY CURRENT             |                             |           |                                                                                         |  |                    |                        |     |      |
| I <sub>CC1</sub>           | ISO7230C/M                  | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN at 3 V              |  |                    | 0.5                    | 1.2 | mA   |
|                            |                             | 25 Mbps   |                                                                                         |  |                    | 3                      | 5   |      |
|                            | ISO7231C/M                  | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN1 at 3 V, EN2 at 3 V |  |                    | 4.5                    | 7   | mA   |
|                            |                             | 25 Mbps   |                                                                                         |  |                    | 6.5                    | 11  |      |
| I <sub>CC2</sub>           | ISO7230C/M                  | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN at 3 V              |  |                    | 15                     | 22  | mA   |
|                            |                             | 25 Mbps   |                                                                                         |  |                    | 17                     | 24  |      |
|                            | ISO7231C/M                  | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN1 at 3 V, EN2 at 3 V |  |                    | 13                     | 20  | mA   |
|                            |                             | 25 Mbps   |                                                                                         |  |                    | 17.5                   | 27  |      |
| ELECTRICAL CHARACTERISTICS |                             |           |                                                                                         |  |                    |                        |     |      |
| I <sub>OFF</sub>           | Sleep mode output current   |           | ENx at 0 V, Single channel                                                              |  |                    | 0                      |     | μA   |
| V <sub>OH</sub>            | High-level output voltage   |           | I <sub>OH</sub> = −4 mA, See <a href="#">Figure 7-1</a>                                 |  | ISO7230            | V <sub>CC0</sub> − 0.4 |     | V    |
|                            |                             |           | I <sub>OH</sub> = −20 μA, See <a href="#">Figure 7-1</a>                                |  | ISO7231 (5-V side) | V <sub>CC0</sub> − 0.8 |     |      |
|                            |                             |           |                                                                                         |  |                    | V <sub>CC0</sub> − 0.1 |     |      |
| V <sub>OL</sub>            | Low-level output voltage    |           | I <sub>OL</sub> = 4 mA, See <a href="#">Figure 7-1</a>                                  |  |                    | 0.4                    |     | V    |
|                            |                             |           | I <sub>OL</sub> = 20 μA, See <a href="#">Figure 7-1</a>                                 |  |                    | 0.1                    |     |      |
| V <sub>I(HYS)</sub>        | Input voltage hysteresis    |           |                                                                                         |  |                    | 150                    |     | mV   |
| I <sub>IH</sub>            | High-level input current    |           | INx at V <sub>CC1</sub>                                                                 |  |                    | 10                     |     | μA   |
| I <sub>IL</sub>            | Low-level input current     |           | INx at 0 V                                                                              |  |                    | −10                    |     |      |
| C <sub>I</sub>             | Input capacitance to ground |           | IN at V <sub>CC</sub> , V <sub>I</sub> = 0.4 sin (2πft), f=2MHz                         |  |                    | 2                      |     | pF   |



over recommended operating conditions (unless otherwise noted)<sup>(1)</sup>

| PARAMETER |                                | TEST CONDITIONS                                        | MIN | TYP | MAX | UNIT        |
|-----------|--------------------------------|--------------------------------------------------------|-----|-----|-----|-------------|
| CMTI      | Common-mode transient immunity | $V_I = V_{CC1}$ or 0 V, See <a href="#">Figure 7-4</a> | 25  | 50  |     | kV/ $\mu$ s |

- (1) For the 5-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 4.5 V to 5.5 V.  
For the 3.3-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 3.15 V to 3.6 V.

## 6.12 Electrical Characteristics: $V_{CC1}$ at 5-V, $V_{CC2}$ at 3.3-V

over recommended operating conditions (unless otherwise noted)<sup>(1)</sup>

| PARAMETER                  |                                |           | TEST CONDITIONS                                                                         |  | MIN                | TYP                    | MAX | UNIT  |
|----------------------------|--------------------------------|-----------|-----------------------------------------------------------------------------------------|--|--------------------|------------------------|-----|-------|
| SUPPLY CURRENT             |                                |           |                                                                                         |  |                    |                        |     |       |
| I <sub>CC1</sub>           | ISO7230C/M                     | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN at 3 V              |  |                    | 1                      | 3   | mA    |
|                            |                                | 25 Mbps   |                                                                                         |  |                    | 7                      | 9.5 |       |
|                            | ISO7231C/M                     | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN1 at 3 V, EN2 at 3 V |  |                    | 6.5                    | 11  | mA    |
|                            |                                | 25 Mbps   |                                                                                         |  |                    | 11                     | 17  |       |
| I <sub>CC2</sub>           | ISO7230C/M                     | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN at 3 V              |  |                    | 9                      | 15  | mA    |
|                            |                                | 25 Mbps   |                                                                                         |  |                    | 10                     | 17  |       |
|                            | ISO7231C/M                     | Quiescent | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, all channels, no load, EN1 at 3 V, EN2 at 3 V |  |                    | 8                      | 12  | mA    |
|                            |                                | 25 Mbps   |                                                                                         |  |                    | 10.5                   | 16  |       |
| ELECTRICAL CHARACTERISTICS |                                |           |                                                                                         |  |                    |                        |     |       |
| I <sub>OFF</sub>           | Sleep mode output current      |           | ENx at 0 V, Single channel                                                              |  |                    | 0                      |     | μA    |
| V <sub>OH</sub>            | High-level output voltage      |           | I <sub>OH</sub> = −4 mA, See <a href="#">Figure 7-1</a>                                 |  | ISO7230            | V <sub>CCO</sub> − 0.4 |     | V     |
|                            |                                |           |                                                                                         |  | ISO7231 (5-V side) | V <sub>CCO</sub> − 0.8 |     |       |
|                            |                                |           | I <sub>OH</sub> = −20 μA, See <a href="#">Figure 7-1</a>                                |  |                    | V <sub>CCO</sub> − 0.1 |     |       |
| V <sub>OL</sub>            | Low-level output voltage       |           | I <sub>OL</sub> = 4 mA, See <a href="#">Figure 7-1</a>                                  |  |                    | 0.4                    |     | V     |
|                            |                                |           | I <sub>OL</sub> = 20 μA, See <a href="#">Figure 7-1</a>                                 |  |                    | 0.1                    |     |       |
| V <sub>I(HYS)</sub>        | Input voltage hysteresis       |           |                                                                                         |  |                    | 150                    |     | mV    |
| I <sub>IH</sub>            | High-level input current       |           | INx at V <sub>CC1</sub>                                                                 |  |                    | 10                     |     | μA    |
| I <sub>IL</sub>            | Low-level input current        |           | INx at 0 V                                                                              |  |                    | −10                    |     |       |
| C <sub>I</sub>             | Input capacitance to ground    |           | IN at V <sub>CC</sub> , V <sub>I</sub> = 0.4 sin (2πft), f=2MHz                         |  |                    | 2                      |     | pF    |
| CMTI                       | Common-mode transient immunity |           | V <sub>I</sub> = V <sub>CC1</sub> or 0 V, See <a href="#">Figure 7-4</a>                |  |                    | 25                     | 50  | kV/μs |

- (1) For the 5-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 4.5 V to 5.5 V.  
For the 3.3-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 3.15 V to 3.6 V.

## 6.13 Switching Characteristics: $V_{CC1}$ and $V_{CC2}$ at 3.3-V

over recommended operating conditions (unless otherwise noted)

| PARAMETER                           |                                                                            |          | TEST CONDITIONS                                                                   | MIN | TYP | MAX | UNIT |
|-------------------------------------|----------------------------------------------------------------------------|----------|-----------------------------------------------------------------------------------|-----|-----|-----|------|
| t <sub>PLH</sub> , t <sub>PHL</sub> | Propagation delay                                                          | ISO723xC | See Figure 7-1                                                                    | 25  |     | 56  | ns   |
| PWD                                 | Pulse-width distortion <sup>(1)</sup>  t <sub>PHL</sub> – t <sub>PLH</sub> |          |                                                                                   |     |     | 4   |      |
| t <sub>PLH</sub> , t <sub>PHL</sub> | Propagation delay                                                          | ISO723xM |                                                                                   | 8   |     | 34  | ns   |
| PWD                                 | Pulse-width distortion <sup>(1)</sup>  t <sub>PHL</sub> – t <sub>PLH</sub> |          |                                                                                   |     |     | 1   |      |
| t <sub>sk(pp)</sub>                 | Part-to-part skew <sup>(2)</sup>                                           | ISO723xC |                                                                                   |     |     | 10  | ns   |
|                                     |                                                                            | ISO723xM |                                                                                   |     |     | 0   |      |
| t <sub>sk(o)</sub>                  | Channel-to-channel output skew <sup>(3)</sup>                              | ISO723xC |                                                                                   |     | 0   | 3   | ns   |
|                                     |                                                                            | ISO723xM |                                                                                   |     |     | 0   |      |
| t <sub>r</sub>                      | Output signal rise time                                                    |          | See Figure 7-1                                                                    |     | 2.4 |     | ns   |
| t <sub>f</sub>                      | Output signal fall time                                                    |          |                                                                                   |     | 2.3 |     |      |
| t <sub>PHZ</sub>                    | Propagation delay, high-level-to-high-impedance output                     |          | See Figure 7-2                                                                    |     | 15  | 25  | ns   |
| t <sub>PZH</sub>                    | Propagation delay, high-impedance-to-high-level output                     |          |                                                                                   |     | 15  | 25  |      |
| t <sub>PLZ</sub>                    | Propagation delay, low-level-to-high-impedance output                      |          |                                                                                   |     | 15  | 25  |      |
| t <sub>PZL</sub>                    | Propagation delay, high-impedance-to-low-level output                      |          |                                                                                   |     | 15  | 25  |      |
| t <sub>fs</sub>                     | Failsafe output delay time from input power loss                           |          | See Figure 7-3                                                                    |     | 18  |     | μs   |
| t <sub>jit(pp)</sub>                | Peak-to-peak eye-pattern jitter                                            | ISO723xM | 150 Mbps PRBS NRZ data input, same polarity input on all channels, See Figure 7-5 |     | 1   |     | ns   |

- (1) Also referred to as pulse skew.  
(2)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

- (3)  $t_{sk(o)}$  is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

## 6.14 Switching Characteristics: $V_{CC1}$ and $V_{CC2}$ at 5-V

over recommended operating conditions (unless otherwise noted)

| PARAMETER                           |                                                                            |          | TEST CONDITIONS                                                                                         | MIN | TYP | MAX | UNIT |
|-------------------------------------|----------------------------------------------------------------------------|----------|---------------------------------------------------------------------------------------------------------|-----|-----|-----|------|
| t <sub>PLH</sub> , t <sub>PHL</sub> | Propagation delay                                                          | ISO723xC | See <a href="#">Figure 7-1</a>                                                                          | 18  |     | 42  | ns   |
| PWD                                 | Pulse-width distortion <sup>(1)</sup>  t <sub>PHL</sub> – t <sub>PLH</sub> |          |                                                                                                         |     | 2.5 |     |      |
| t <sub>PLH</sub> , t <sub>PHL</sub> | Propagation delay                                                          | ISO723xM |                                                                                                         | 8   |     | 23  | ns   |
| PWD                                 | Pulse-width distortion <sup>(1)</sup>  t <sub>PHL</sub> – t <sub>PLH</sub> |          |                                                                                                         | 1   | 2   |     |      |
| t <sub>sk(pp)</sub>                 | Part-to-part skew <sup>(2)</sup>                                           | ISO723xC |                                                                                                         |     |     | 8   | ns   |
|                                     |                                                                            | ISO723xM |                                                                                                         | 0   | 3   |     |      |
| t <sub>sk(o)</sub>                  | Channel-to-channel output skew <sup>(3)</sup>                              | ISO723xC |                                                                                                         |     | 0   | 2   | ns   |
|                                     |                                                                            | ISO723xM |                                                                                                         |     | 0   | 1   |      |
| t <sub>r</sub>                      | Output signal rise time                                                    |          | See <a href="#">Figure 7-1</a>                                                                          |     | 2.4 |     | ns   |
| t <sub>f</sub>                      | Output signal fall time                                                    |          |                                                                                                         |     | 2.3 |     |      |
| t <sub>PHZ</sub>                    | Propagation delay, high-level-to-high-impedance output                     |          | See <a href="#">Figure 7-2</a>                                                                          |     | 15  | 25  | ns   |
| t <sub>PZH</sub>                    | Propagation delay, high-impedance-to-high-level output                     |          |                                                                                                         |     | 15  | 25  |      |
| t <sub>PLZ</sub>                    | Propagation delay, low-level-to-high-impedance output                      |          |                                                                                                         |     | 15  | 25  |      |
| t <sub>PZL</sub>                    | Propagation delay, high-impedance-to-low-level output                      |          |                                                                                                         |     | 15  | 25  |      |
| t <sub>fs</sub>                     | Failsafe output delay time from input power loss                           |          | See <a href="#">Figure 7-3</a>                                                                          |     | 12  |     | μs   |
| t <sub>jitt(pp)</sub>               | Peak-to-peak eye-pattern jitter                                            | ISO723xM | 150 Mbps PRBS NRZ data input,<br>Same polarity input on all channels,<br>See <a href="#">Figure 7-5</a> |     | 1   |     | ns   |

(1) Also referred to as pulse skew.

(2)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

(3)  $t_{sk(o)}$  is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

## 6.15 Switching Characteristics: $V_{CC1}$ at 3.3-V and $V_{CC2}$ at 5-V

, over recommended operating conditions (unless otherwise noted)

| PARAMETER                           |                                                                            |          | TEST CONDITIONS                                                                   | MIN | TYP | MAX | UNIT |
|-------------------------------------|----------------------------------------------------------------------------|----------|-----------------------------------------------------------------------------------|-----|-----|-----|------|
| t <sub>PLH</sub> , t <sub>PHL</sub> | Propagation delay                                                          | ISO723xC | See Figure 7-1                                                                    | 22  |     | 51  | ns   |
| PWD                                 | Pulse-width distortion <sup>(1)</sup>  t <sub>PHL</sub> – t <sub>PLH</sub> |          |                                                                                   |     |     | 3   |      |
| t <sub>PLH</sub> , t <sub>PHL</sub> | Propagation delay                                                          | ISO723xM |                                                                                   | 8   |     | 30  |      |
| PWD                                 | Pulse-width distortion <sup>(1)</sup>  t <sub>PHL</sub> – t <sub>PLH</sub> |          |                                                                                   |     | 1   | 2   |      |
| t <sub>sk(pp)</sub>                 | Part-to-part skew <sup>(2)</sup>                                           | ISO723xC |                                                                                   |     | 10  | ns  |      |
|                                     |                                                                            | ISO723xM |                                                                                   | 0   | 5   |     |      |
| t <sub>sk(o)</sub>                  | Channel-to-channel output skew <sup>(3)</sup>                              | ISO723xC |                                                                                   | 0   | 2.5 | ns  |      |
|                                     |                                                                            | ISO723xM |                                                                                   | 0   | 1   |     |      |
| t <sub>r</sub>                      | Output signal rise time                                                    |          | See Figure 7-1                                                                    |     | 2.4 |     | ns   |
| t <sub>f</sub>                      | Output signal fall time                                                    |          |                                                                                   |     | 2.3 |     |      |
| t <sub>PHZ</sub>                    | Propagation delay, high-level-to-high-impedance output                     |          | See Figure 7-2                                                                    |     | 15  | 25  | ns   |
| t <sub>PZH</sub>                    | Propagation delay, high-impedance-to-high-level output                     |          |                                                                                   |     | 15  | 25  |      |
| t <sub>PLZ</sub>                    | Propagation delay, low-level-to-high-impedance output                      |          |                                                                                   |     | 15  | 25  |      |
| t <sub>PZL</sub>                    | Propagation delay, high-impedance-to-low-level output                      |          |                                                                                   |     | 15  | 25  |      |
| t <sub>fs</sub>                     | Failsafe output delay time from input power loss                           |          |                                                                                   |     | 12  |     | μs   |
| t <sub>jit(pp)</sub>                | Peak-to-peak eye-pattern jitter                                            | ISO723xM | 150 Mbps PRBS NRZ data input, Same polarity input on all channels, See Figure 7-5 |     | 1   |     | ns   |

(1) Also known as pulse skew

(2)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

- (3)  $t_{sk(o)}$  is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

## 6.16 Switching Characteristics: $V_{CC1}$ at 5-V, $V_{CC2}$ at 3.3-V

over recommended operating conditions (unless otherwise noted)

| PARAMETER                           |                                                                            |          | TEST CONDITIONS                                                                   | MIN | TYP | MAX | UNIT |
|-------------------------------------|----------------------------------------------------------------------------|----------|-----------------------------------------------------------------------------------|-----|-----|-----|------|
| t <sub>PLH</sub> , t <sub>PHL</sub> | Propagation delay, low-to-high-level output                                | ISO723xC | See Figure 7-1                                                                    | 20  |     | 50  | ns   |
| PWD                                 | Pulse-width distortion <sup>(1)</sup>  t <sub>PHL</sub> – t <sub>PLH</sub> |          |                                                                                   |     |     | 3   |      |
| t <sub>PLH</sub> , t <sub>PHL</sub> | Propagation delay, low-to-high-level output                                | ISO723xM |                                                                                   | 8   |     | 29  | ns   |
| PWD                                 | Pulse-width distortion <sup>(1)</sup>  t <sub>PHL</sub> – t <sub>PLH</sub> |          |                                                                                   |     | 1   | 2   |      |
| t <sub>sk(pp)</sub>                 | Part-to-part skew <sup>(2)</sup>                                           | ISO723xC |                                                                                   |     |     | 10  | ns   |
|                                     |                                                                            | ISO723xM |                                                                                   |     | 0   | 5   |      |
| t <sub>sk(o)</sub>                  | Channel-to-channel output skew <sup>(3)</sup>                              | ISO723xC |                                                                                   |     | 0   | 2.5 | ns   |
|                                     |                                                                            | ISO723xM |                                                                                   |     | 0   | 1   |      |
| t <sub>r</sub>                      | Output signal rise time                                                    |          | See Figure 7-1                                                                    |     | 2.4 |     | ns   |
| t <sub>f</sub>                      | Output signal fall time                                                    |          |                                                                                   |     | 2.3 |     |      |
| t <sub>PHZ</sub>                    | Propagation delay, high-level-to-high-impedance output                     |          | See Figure 7-2                                                                    |     | 15  | 25  | ns   |
| t <sub>PZH</sub>                    | Propagation delay, high-impedance-to-high-level output                     |          |                                                                                   |     | 15  | 25  |      |
| t <sub>PLZ</sub>                    | Propagation delay, low-level-to-high-impedance output                      |          |                                                                                   |     | 15  | 25  |      |
| t <sub>PZL</sub>                    | Propagation delay, high-impedance-to-low-level output                      |          |                                                                                   |     | 15  | 25  |      |
| t <sub>fs</sub>                     | Failsafe output delay time from input power loss                           |          | See Figure 7-3                                                                    |     | 18  |     | μs   |
| t <sub>jit(pp)</sub>                | Peak-to-peak eye-pattern jitter                                            | ISO723xM | 150 Mbps PRBS NRZ data input, Same polarity input on all channels, See Figure 7-5 |     |     | 1   | ns   |

- (1) Also known as pulse skew  
 (2)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.  
 (3)  $t_{sk(o)}$  is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

## 6.17 Typical Characteristics

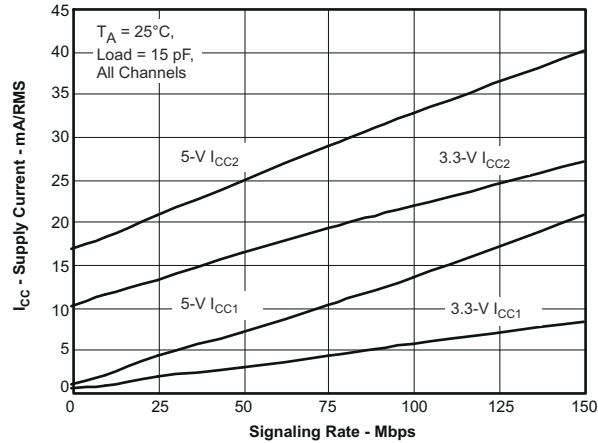


Figure 6-1. ISO7230C/M RMS Supply Current vs Signaling Rate

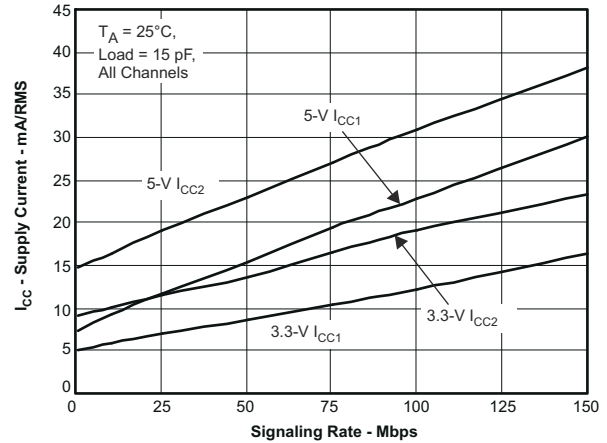


Figure 6-2. ISO7231C/M RMS Supply Current vs Signaling Rate

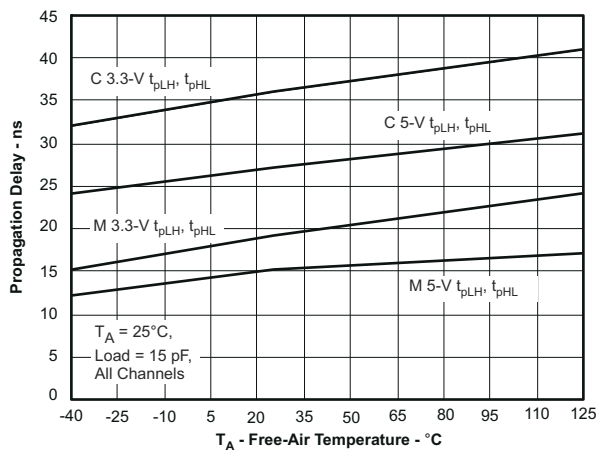


Figure 6-3. Propagation Delay vs Free-Air Temperature

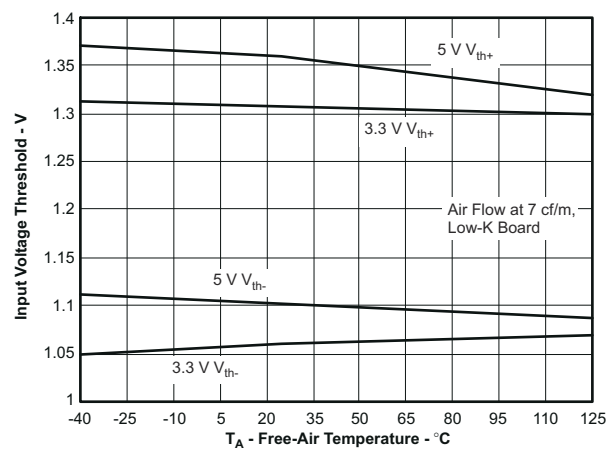


Figure 6-4. Input Threshold Voltage vs Free-Air Temperature

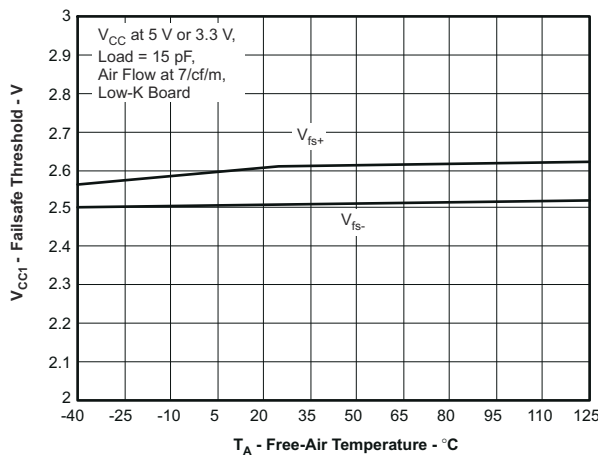


Figure 6-5. VCC1 Fail-Safe Threshold vs Free-Air Temperature

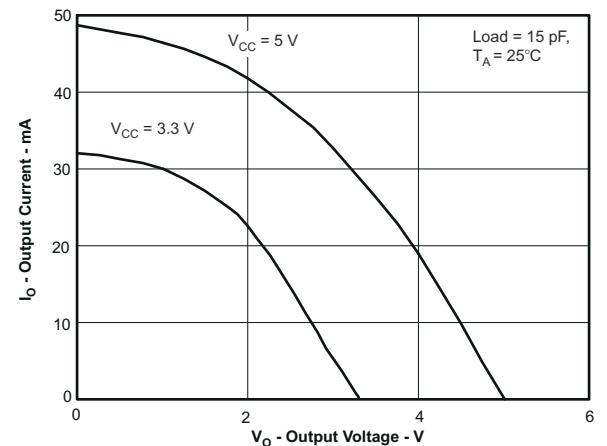
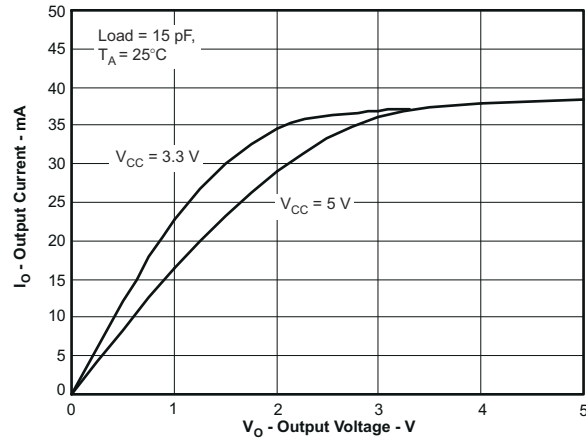


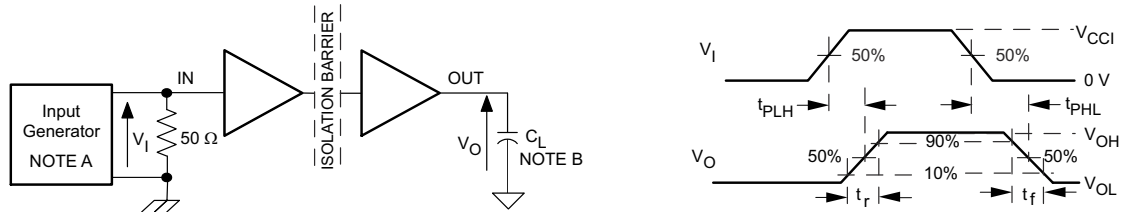
Figure 6-6. High-Level Output Current vs High-Level Output Voltage

## 6.17 Typical Characteristics (continued)



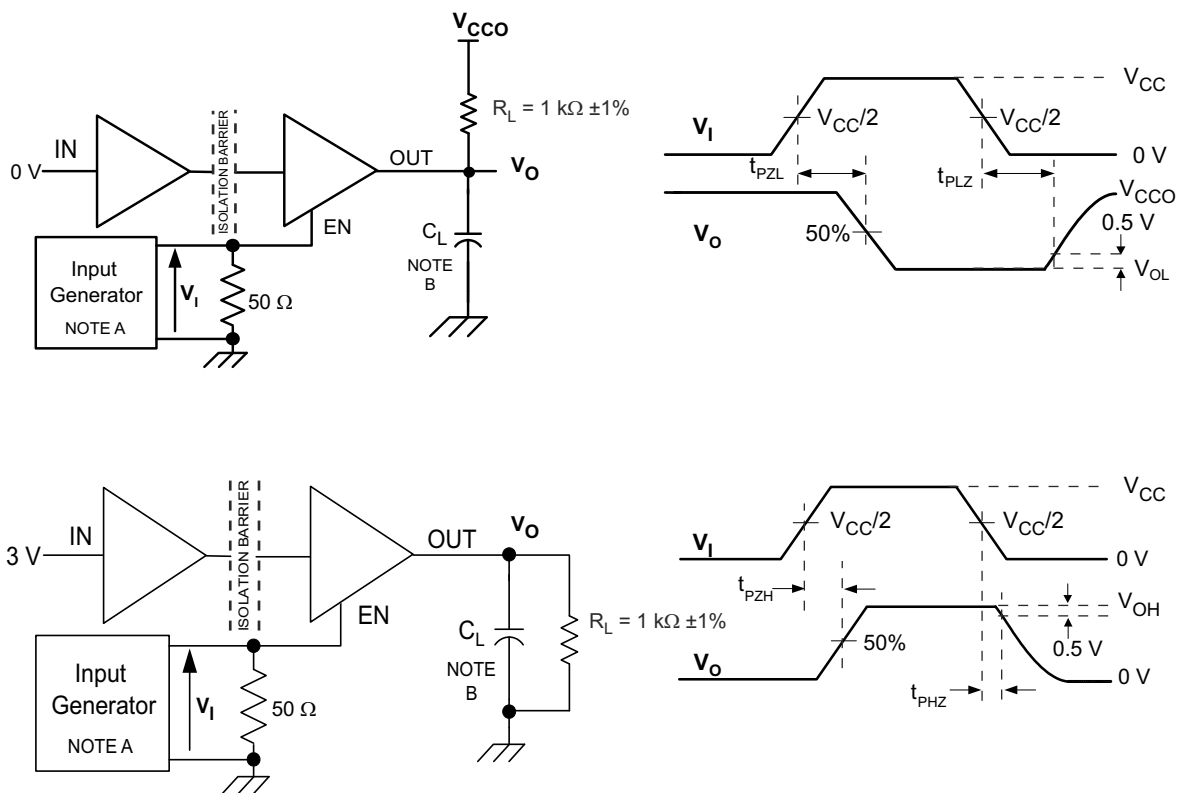
**Figure 6-7. Low-Level Output Current vs Low-Level Output Voltage**

## 7 Parameter Measurement Information



- A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq 50$  kHz, 50% duty cycle,  $t_r \leq 3$  ns,  $t_f \leq 3$  ns,  $Z_O = 50 \Omega$ . At the input, a  $50\text{-}\Omega$  resistor is required to terminate the Input Generator signal. The  $50\text{-}\Omega$  is not needed in actual application.
- B.  $C_L = 15$  pF and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

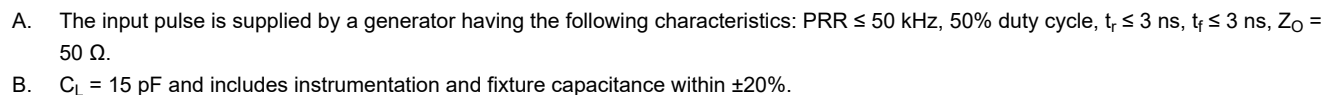
**Figure 7-1. Switching Characteristic Test Circuit and Voltage Waveforms**



- A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq 50$  kHz, 50% duty cycle,  $t_r \leq 3$  ns,  $t_f \leq 3$  ns,  $Z_O = 50\Omega$ .
- B.  $C_L = 15$  pF and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

**Figure 7-2. Enable/Disable Propagation Delay Time Test Circuit and Waveform**





Pass-fail criteria:  
The output must remain stable.

See Note A

- A.  $C_l = 15$  pF and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

The figure consists of two parts. The left part is a block diagram showing a Tektronix HFS9009 PATTERN GENERATOR connected to the IN of a DUT (Device Under Test). The DUT contains a buffer and an inverter. The OUT of the DUT is connected to a Tektronix 784D oscilloscope. The right part is a timing diagram showing the Input and Output signals. The Input signal is a square wave between  $V_{CC}$  and 0 V. The Output signal is a square wave between 0 V and  $V_{CC}/2$ . The jitter is indicated by the time difference between the rising edges of the Input and Output signals.

PRBS bit pattern run length is  $2^{16} - 1$ . Transition time is 800 ps. NRZ data input has no more than five consecutive 1s or 0s.

### Figure 7-5. Peak-to-Peak Eye-Pattern Jitter Test Circuit and Voltage Waveform

## 8 Detailed Description

### 8.1 Overview

The ISO723x family of devices transmit digital data across a silicon dioxide based isolation barrier. The digital input signal (IN) of the device is sampled by a transmitter and at every data edge the transmitter sends a corresponding differential signal across the isolation barrier. When the input signal is static, the refresh logic periodically sends the necessary differential signal from the transmitter. On the other side of the isolation barrier, the receiver converts the differential signal into a single-ended signal which is output on the OUT pin through a buffer. If the receiver does not receive a data or refresh signal, the timeout logic detects the loss of signal or power from the input side and drives the output to the default level.

### 8.2 Functional Block Diagram

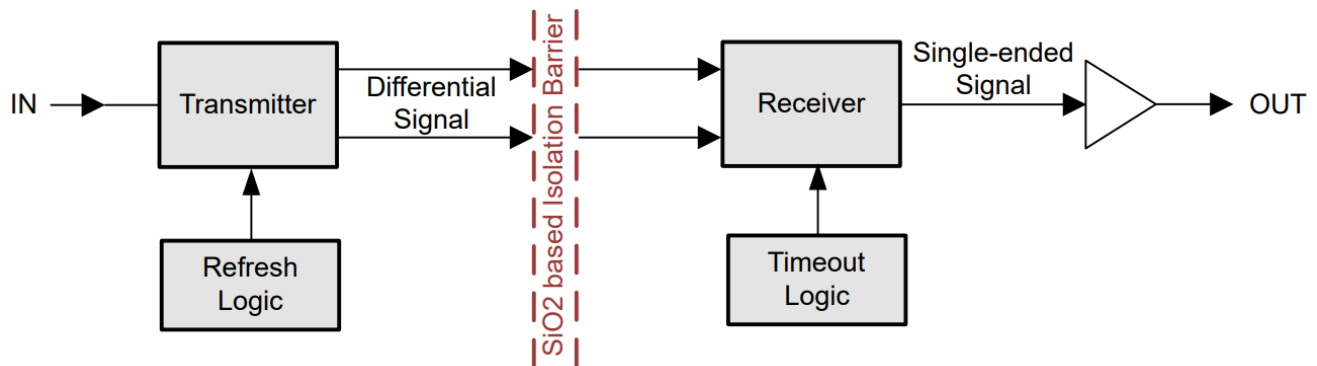


Figure 8-1. Conceptual Block Diagram of a Digital Isolator

### 8.3 Feature Description

The ISO724x-Q1 family of devices is available in multiple channel configurations and default output-state options to enable wide variety of application uses. [Table 8-1](#) lists these device features.

**Table 8-1. Device Features**

| PRODUCT <sup>(1)</sup> | SIGNALING RATE | INPUT THRESHOLD | CHANNEL CONFIGURATION |
|------------------------|----------------|-----------------|-----------------------|
| ISO7240CF              | 25 Mbps        | ≈1.5 V (TTL)    | 4/0                   |
| ISO7241C               | 25 Mbps        | ≈1.5 V (TTL)    | 3/1                   |
| ISO7242C               | 25 Mbps        | ≈1.5 V (TTL)    | 2/2                   |

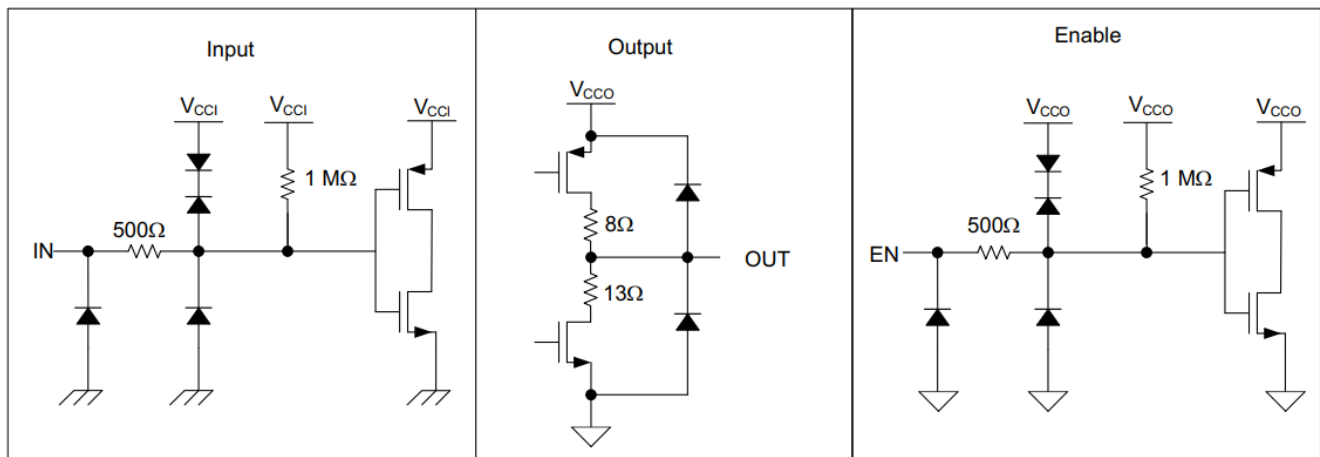
### 8.4 Device Functional Modes

List of ISO7231C-Q1 functional modes.

**Table 8-2. Device Function Table ISO7231C-Q1**

| INPUT V <sub>CC</sub> | OUTPUT V <sub>CC</sub> | INPUT (IN) | OUTPUT ENABLE (EN) | OUTPUT (OUT) |
|-----------------------|------------------------|------------|--------------------|--------------|
| PU                    | PU                     | H          | H or Open          | H            |
|                       |                        | L          | H or Open          | L            |
|                       |                        | X          | L                  | Z            |
|                       |                        | Open       | H or Open          | H            |
| PD                    | PU                     | X          | H or Open          | H            |
| PD                    | PU                     | X          | L                  | Z            |
| X                     | PD                     | X          | X                  | Undetermined |

#### 8.4.1 Device I/O Schematics



**Figure 8-2. Device I/O Schematics**

## 9 Application and Implementation

### Note

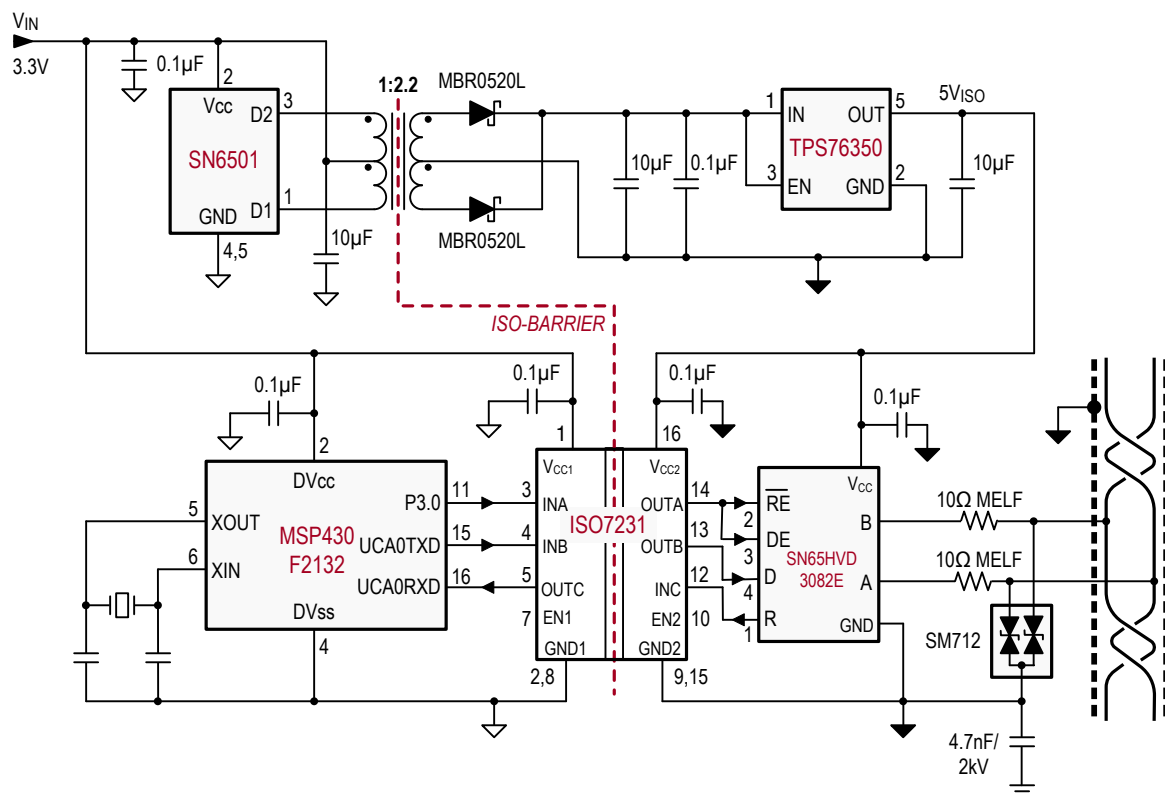
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

## 9.1 Application Information

ISO723x utilize single-ended TTL or CMOS-logic switching technologies. The supply voltage range is from 3.15 V to 5.5 V for both supplies,  $V_{CC1}$  and  $V_{CC2}$ . When designing with digital isolators keep in mind that due to the single-ended design structure, digital isolators do not conform to any specific interface standard and are only intended for isolating single-ended CMOS or TTL digital signal lines. The isolator is typically placed between the data controller (that is,  $\mu C$  or UART), and a data converter or a line transceiver, regardless of the interface type or standard.

## 9.2 Typical Application

ISO7231 combined with Texas Instruments' mixed signal micro-controller, RS-485 transceiver, transformer driver, and voltage regulator can create an isolated RS-485 system as shown in [Figure 9-1](#).



### Figure 9-1. Isolated RS-485 Application Circuit

### 9.2.1 Design Requirements

Unlike optocouplers, which need external components to improve performance, provide bias, or limit current, ISO723x only needs two external bypass capacitors to operate.

## 9.2.2 Detailed Design Procedure

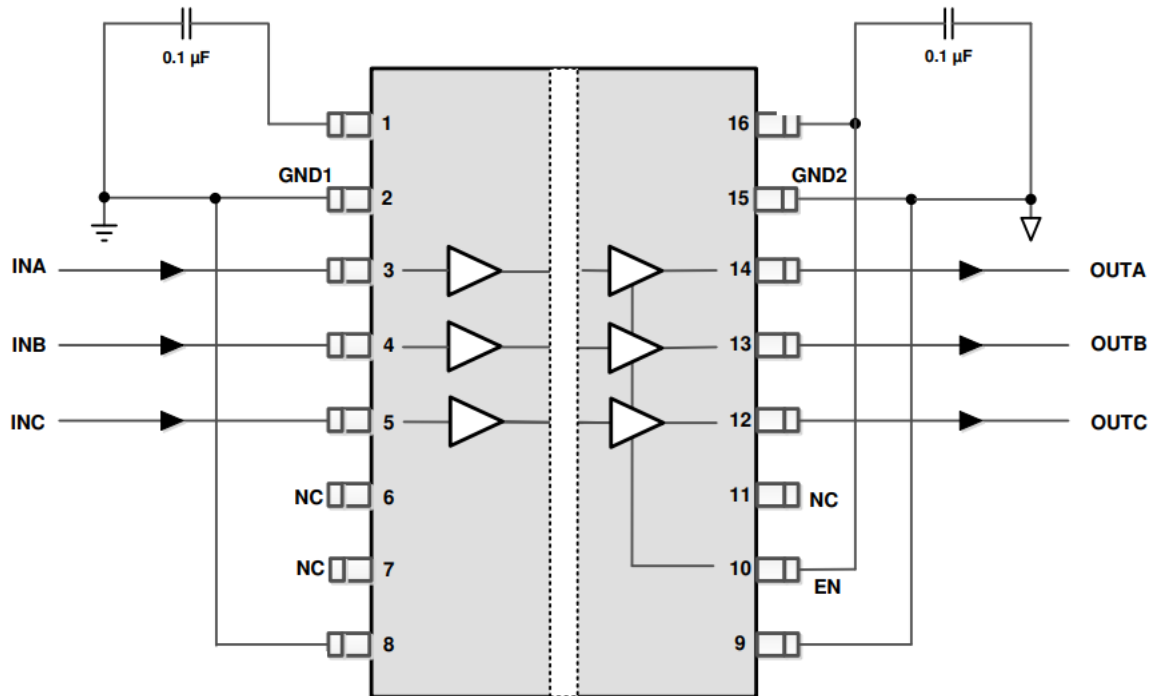


Figure 9-2. Typical ISO7231-Q1 Circuit Hook-up

## 9.2.3 Application Performance Plots

### 9.2.3.1 Insulation Characteristics Curves

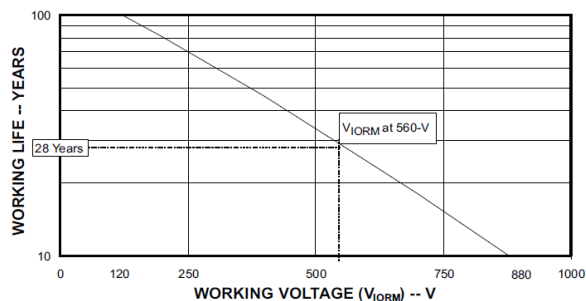


Figure 9-3. Isolation Lifetime Projection

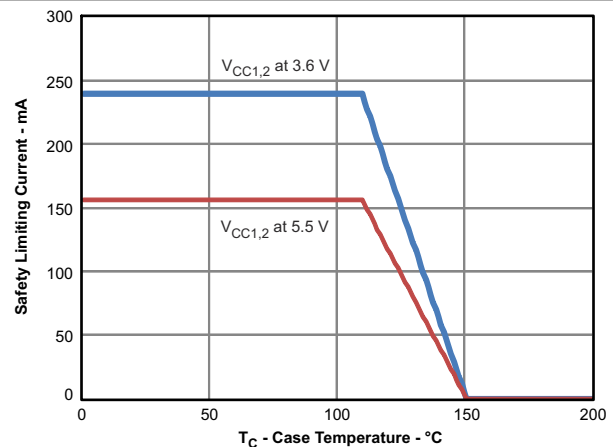


Figure 9-4. Thermal Derating Curve for Limiting Current per VDE

## 9.3 Power Supply Recommendations

To provide reliable operation at all data rates and supply voltages, a 0.1 µF bypass capacitor is recommended at input and output supply pins ( $V_{CC1}$  and  $V_{CC2}$ ). The capacitors must be placed as close to the supply pins as possible. If only a single primary-side power supply is available in an application, isolated power can be generated for the secondary-side with the help of a transformer driver such as Texas Instruments SN6501 data

sheet. For such applications, detailed power supply design and transformer selection recommendations are available in the [SN6501 data sheet](#).

## 9.4 Layout

### 9.4.1 Layout Guidelines

A minimum of four layers is required to accomplish a low EMI PCB design (see [Figure 9-5](#)). Layer stacking must be in the following order (top-to-bottom): high-speed signal layer, ground plane, power plane and low-frequency signal layer.

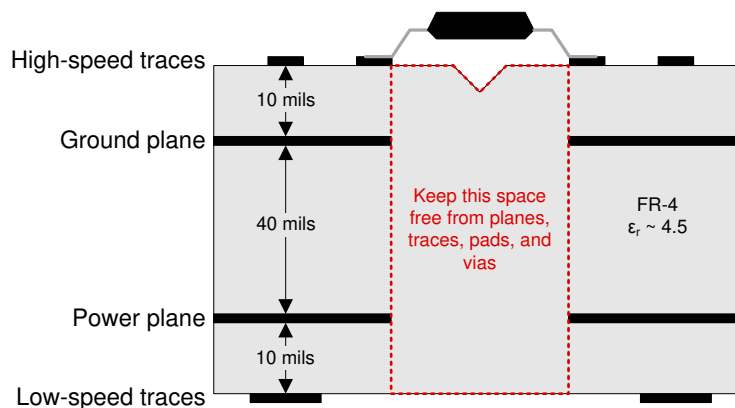
- Routing the high-speed traces on the top layer avoids the use of vias (and the introduction of the inductances) and allows for clean interconnects between the isolator and the transmitter and receiver circuits of the data link.
- Placing a solid ground plane next to the high-speed signal layer establishes controlled impedance for transmission line interconnects and provides an excellent low-inductance path for the return current flow.
- Placing the power plane next to the ground plane creates additional high-frequency bypass capacitance of approximately 100pF/in<sup>2</sup>.
- Routing the slower speed control signals on the bottom layer allows for greater flexibility as these signal links typically have margin to tolerate discontinuities such as vias.

If an additional supply voltage plane or signal layer is needed, add a second power/ground plane system to the stack to keep the planes symmetrical. This makes the stack mechanically stable and prevents warping. Also the power and ground plane of each power system can be placed closer together, thus increasing the high-frequency bypass capacitance significantly. For detailed layout recommendations, see Application Note [SLLA284](#), *Digital Isolator Design Guide*.

#### 9.4.1.1 PCB Material

For digital circuit boards operating below 150 Mbps, (or rise and fall times higher than 1 ns), and trace lengths of up to 10 inches, use standard FR-4 epoxy-glass as PCB material. FR-4 (Flame Retardant 4) meets the requirements of Underwriters Laboratories UL94-V0, and is preferred over cheaper alternatives due to the lower dielectric losses at high frequencies, less moisture absorption, greater strength and stiffness, and the self-extinguishing flammability-characteristics.

#### 9.4.2 Layout Example



**Figure 9-5. Recommended Layer Stack**

## 10 Device and Documentation Support

### 10.1 Documentation Support

#### 10.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [Isolation Glossary](#), application note
- Texas Instruments, [How to use isolation to improve ESD, EFT, and Surge immunity in industrial systems](#), application note
- Texas Instruments, [Digital Isolator Design Guide](#) application note

### 10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](#). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 10.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

### 10.4 Trademarks

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DeviceNet™ is a trademark of Open DeviceNet Vendors Association.

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

### 10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 10.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 11 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Revision M (February 2025) to Revision N (October 2025)                                                                                                                                                               | Page |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|
| • Fixed typos and errors in <i>Insulation Specifications</i> table.....                                                                                                                                                            | 4    |
| • Changed 'Plan to certify' with 'Certified' in all 3 places in the 2nd row in the <i>Safety-Related Certifications</i> section.....                                                                                               | 4    |
| • Changed 'Certificate planned' with 'Basic certificate: 40047657' in VDE column, 'Master contract number: 220991' in CSA column, and 'File number: E181974' in UL column in the <i>Safety-Related Certifications</i> section..... | 4    |

| Changes from Revision L (October 2024) to Revision M (February 2025)                                  | Page |
|-------------------------------------------------------------------------------------------------------|------|
| • Updated the numbering format for tables, figures, and cross-references throughout the document..... | 1    |

- 
- Added links to safety-related certifications to the *Features* section..... 1
- 

| <b>Changes from Revision K (October 2015) to Revision L (October 2024)</b>                                                                             | <b>Page</b> |
|--------------------------------------------------------------------------------------------------------------------------------------------------------|-------------|
| • Updated the numbering format for tables, figures, and cross-references throughout the document.....                                                  | 1           |
| • Updated VDE V 0884-11 to DIN VDE 0884-17 throughout the document.....                                                                                | 1           |
| • Updated references from capacitive isolation to isolation barrier throughout the document.....                                                       | 1           |
| • Updated Thermal Characteristics, Safety Limiting Values, and Thermal Derating Curves to provide more accurate system-level thermal calculations..... | 4           |
| • Updated the <i>Regulatory Information</i> table.....                                                                                                 | 7           |
| • Updated electrical and switching characteristics to match device performance.....                                                                    | 7           |
| • Moved the <i>Insulation Characteristics Curves</i> to the <i>Application Curves</i> section.....                                                     | 21          |

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| <b>Changes from Revision J (May 2015) to Revision K (October 2015)</b>                      | <b>Page</b> |
|---------------------------------------------------------------------------------------------|-------------|
| • Changed The ground symbols on the Enable circuit in the Device I/O Schematics images..... | 19          |

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## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



## PACKAGING INFORMATION

| Orderable part number       | Status<br>(1) | Material type<br>(2) | Package   Pins | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-----------------------------|---------------|----------------------|----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">ISO7230CDW</a>  | Obsolete      | Production           | SOIC (DW)   16 | -                     | -           | Call TI                              | Call TI                           | -40 to 125   | ISO7230C            |
| <a href="#">ISO7230CDWR</a> | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | ISO7230C            |
| ISO7230CDWR.A               | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | ISO7230C            |
| ISO7230CDWR.B               | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 125   |                     |
| <a href="#">ISO7230MDW</a>  | Obsolete      | Production           | SOIC (DW)   16 | -                     | -           | Call TI                              | Call TI                           | -40 to 125   | ISO7230M            |
| <a href="#">ISO7230MDWR</a> | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | ISO7230M            |
| ISO7230MDWR.A               | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | ISO7230M            |
| ISO7230MDWR.B               | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 125   |                     |
| <a href="#">ISO7231CDW</a>  | Obsolete      | Production           | SOIC (DW)   16 | -                     | -           | Call TI                              | Call TI                           | -40 to 125   | ISO7231C            |
| <a href="#">ISO7231CDWR</a> | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | ISO7231C            |
| ISO7231CDWR.A               | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | ISO7231C            |
| ISO7231CDWR.B               | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 125   |                     |
| ISO7231CDWRG4               | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | ISO7231C            |
| <a href="#">ISO7231MDW</a>  | Obsolete      | Production           | SOIC (DW)   16 | -                     | -           | Call TI                              | Call TI                           | -40 to 125   | ISO7231M            |
| <a href="#">ISO7231MDWR</a> | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | ISO7231M            |
| ISO7231MDWR.A               | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | ISO7231M            |
| ISO7231MDWR.B               | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 125   |                     |
| ISO7231MDWRG4               | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | ISO7231M            |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

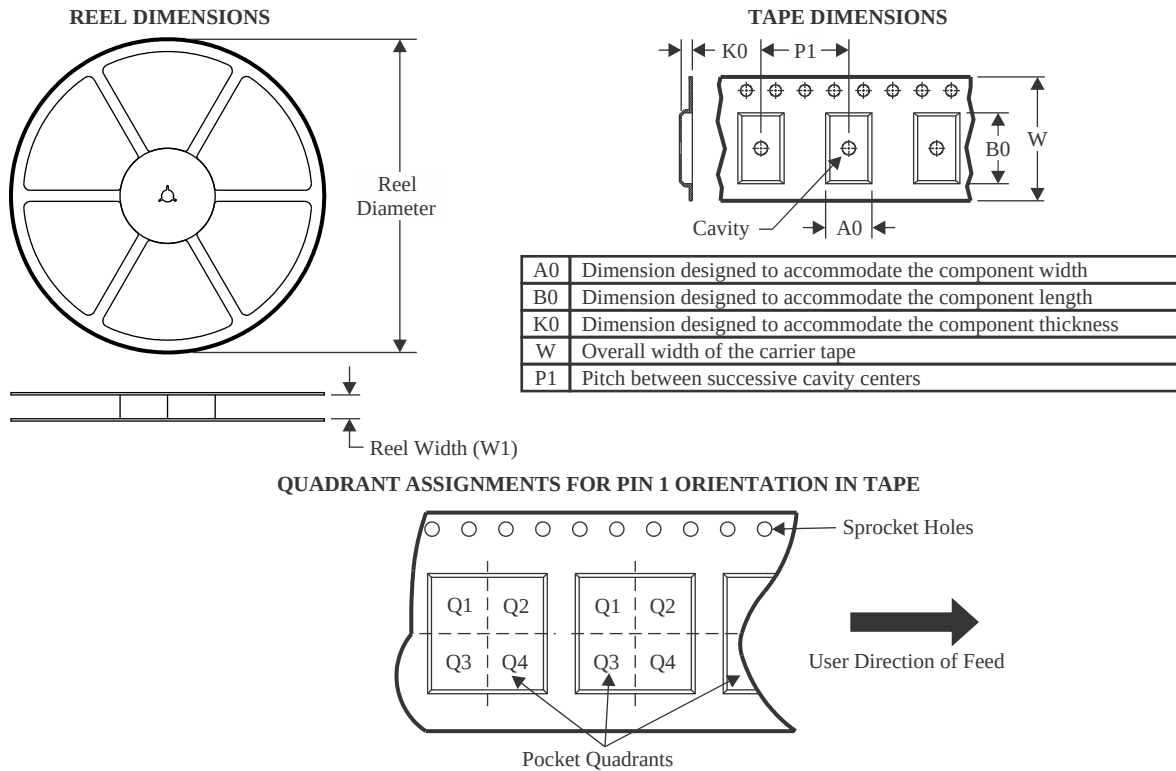
**OTHER QUALIFIED VERSIONS OF ISO7231C :**

- Automotive : [ISO7231C-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

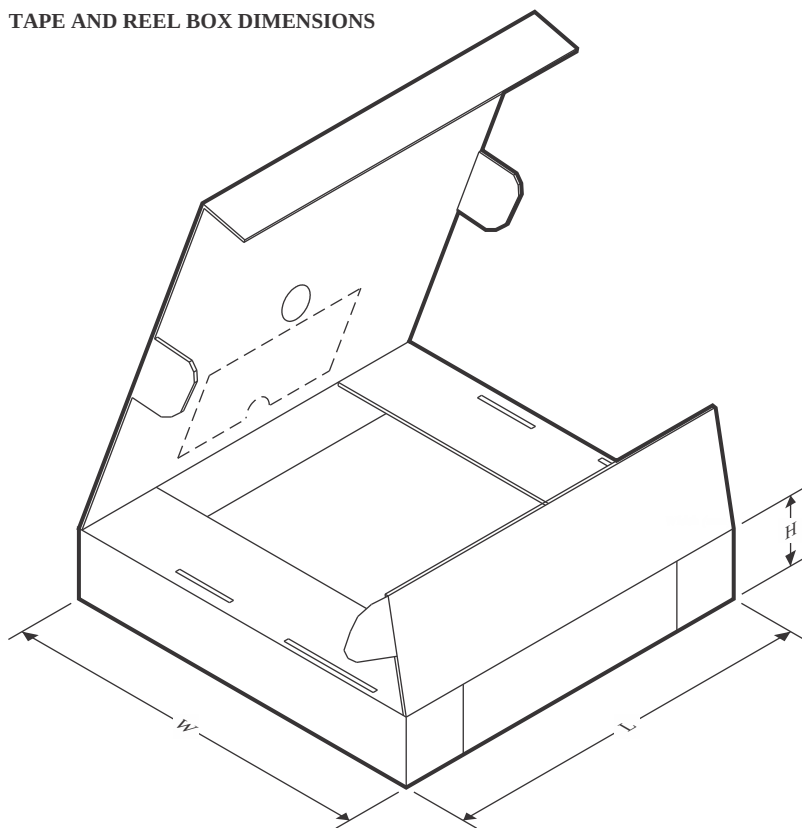
## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device      | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| ISO7230CDWR | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7230MDWR | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7231CDWR | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7231MDWR | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device      | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| ISO7230CDWR | SOIC         | DW              | 16   | 2000 | 350.0       | 350.0      | 43.0        |
| ISO7230MDWR | SOIC         | DW              | 16   | 2000 | 350.0       | 350.0      | 43.0        |
| ISO7231CDWR | SOIC         | DW              | 16   | 2000 | 350.0       | 350.0      | 43.0        |
| ISO7231MDWR | SOIC         | DW              | 16   | 2000 | 350.0       | 350.0      | 43.0        |

## GENERIC PACKAGE VIEW

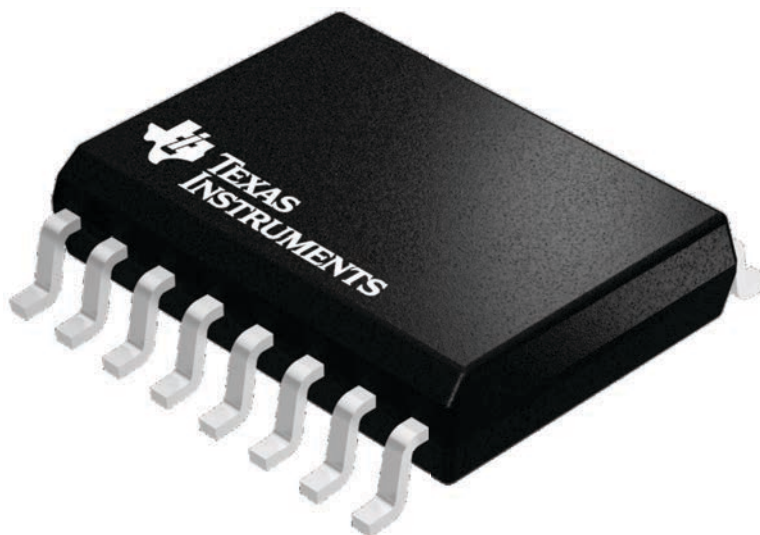
**DW 16**

**SOIC - 2.65 mm max height**

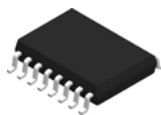
7.5 x 10.3, 1.27 mm pitch

SMALL OUTLINE INTEGRATED CIRCUIT

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4224780/A

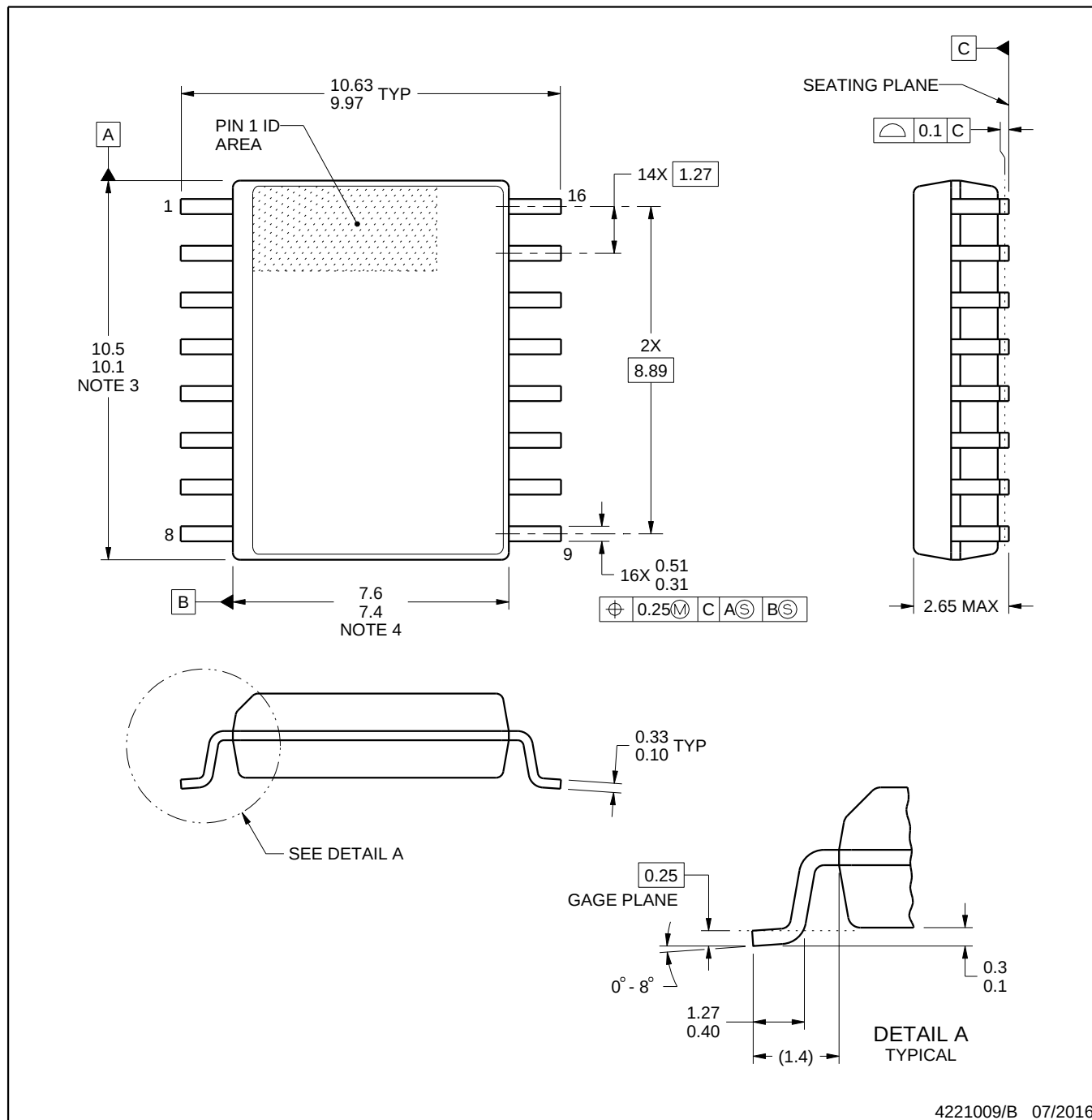


DW0016B

# PACKAGE OUTLINE

## SOIC - 2.65 mm max height

SOIC



4221009/B 07/2016

### NOTES:

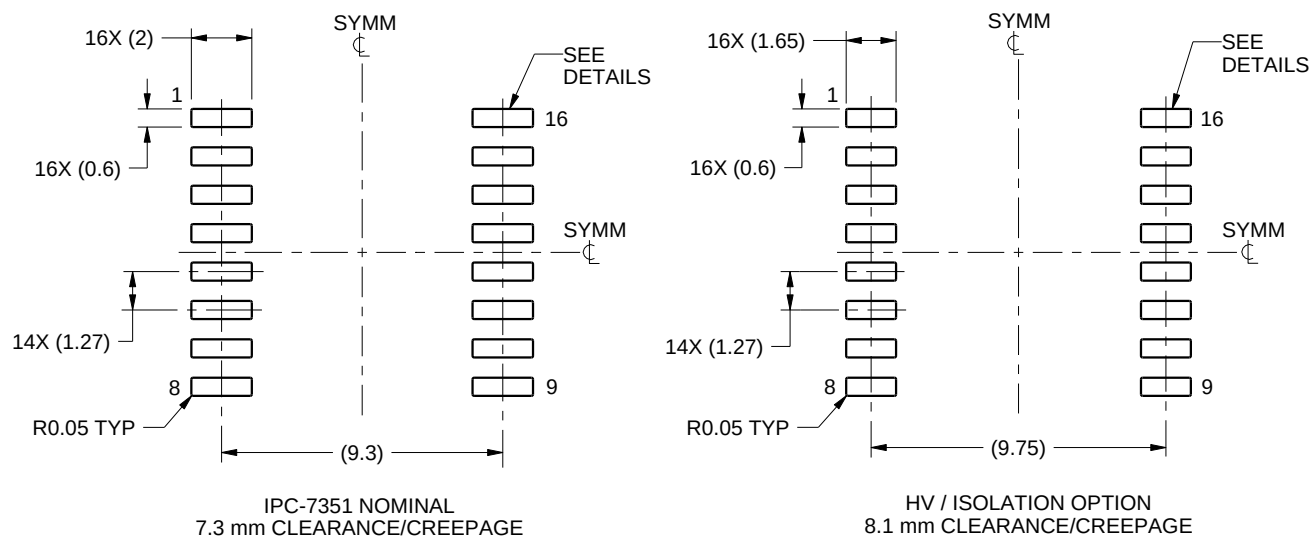
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
5. Reference JEDEC registration MS-013.

# EXAMPLE BOARD LAYOUT

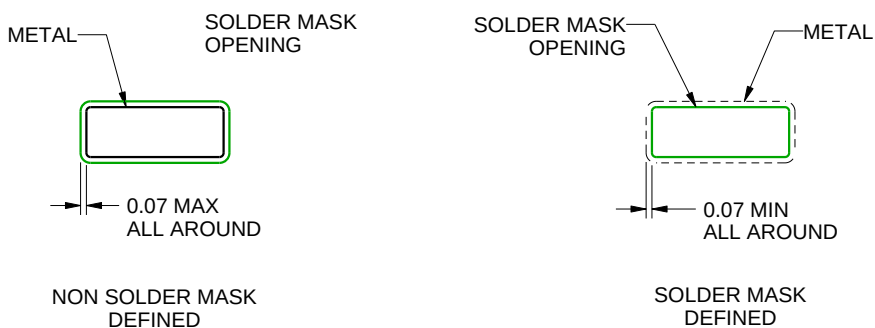
DW0016B

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE  
SCALE:4X



SOLDER MASK DETAILS

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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

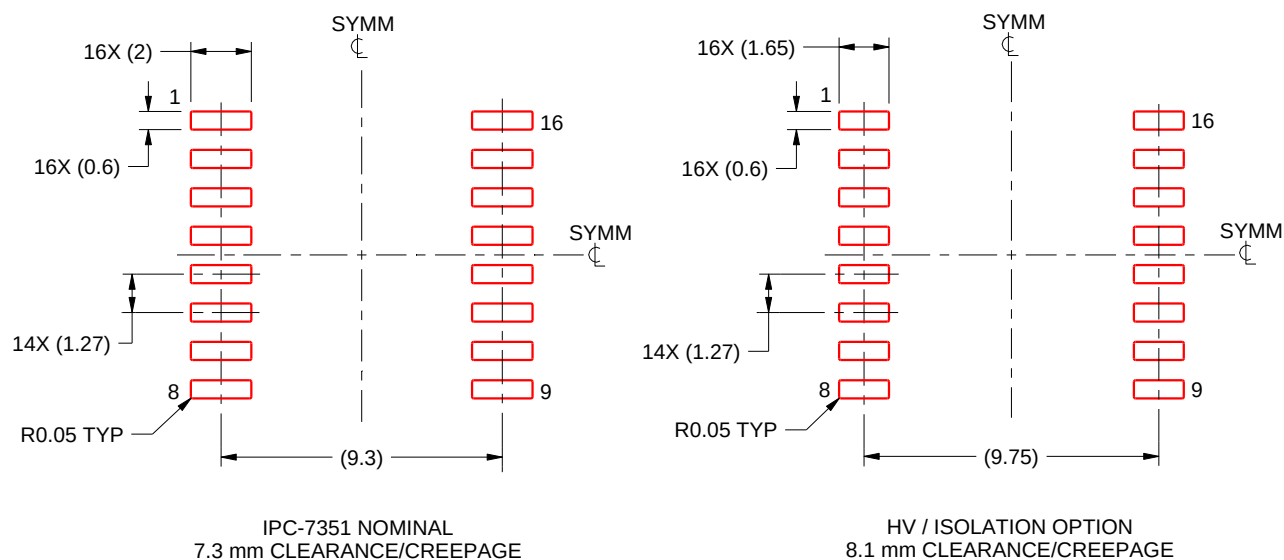
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DW0016B

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:4X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



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